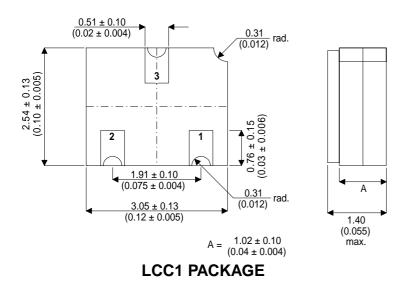
2N4928CSM



GENERAL PURPOSE TRANSISTOR IN A HERMETICALLY SEALED CERAMIC SURFACE MOUNT PACKAGE FOR HIGH RELIABILITY APPLICATIONS

MECHANICAL DATA

Dimensions in mm (inches)



Underside View

PAD 1 – Base

PAD 2 – Emitter PAD 3 – Collector

FEATURES

- SILICON PNP TRANSISTOR
- HERMETIC CERAMIC SURFACE MOUNT PACKAGE (SOT23 COMPATIBLE)
- CECC SCREENING OPTIONS
- SPACE QUALITY LEVELS OPTIONS
- JAN LEVEL SCREENING OPTIONS

APPLICATIONS:

Hermetically sealed surface mount version of the 2N4928 for high reliability / space applications requiring small size and low weight devices.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

| V _{CBO} | Collector – Base Voltage(I _E = 0) | -100V | | | |
|----------------------------------|--|--------------|--|--|--|
| V _{CEO} | Collector – Emitter Voltage ($I_B = 0$) | -100V | | | |
| V _{EBO} | Emitter – Base Voltage (I _C = 0) | -4V | | | |
| I _C | Collector Current | -100mA | | | |
| PD | Total Device Dissipation | 350mW | | | |
| | Derate above 50°C | 2.0mW / °C | | | |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance Junction to Ambient | 500°C/W | | | |
| T _{stg,} T _j | Storage Temperature,Operating Temp Range | –55 to 200°C | | | |

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

| | Parameter | Test Conditions | | Min. | Тур. | Max. | Unit |
|-----------------------|--|-------------------------|-----------------------|------|------|-------|------|
| V _{(BR)CEO*} | Collector – Emitter Breakdown Voltage | I _C = -10mA | I _B = 0 | -100 | | | |
| V _{(BR)CBO*} | Collector – Base Breakdown Voltage | I _C = -100μA | $I_E = 0$ | -100 | | | V |
| V _{(BR)EBO*} | Emitter – Base Breakdown Voltage | I _E = -100μA | $I_{\rm C} = 0$ | -4.0 | | | |
| I _{CBO*} | Collector – Base Cut-off Current | I _B = 0 | $V_{CB} = -50V$ | | | -0.5 | μA |
| I _{EBO*} | Emitter Cut-off Current ($I_C = 0$) | I _C = 0 | $V_{EB} = 3V$ | | | -0.5 | |
| V _{CE(sat)*} | Collector – Emitter Saturation Voltage | I _C = -10mA | I _B = -1mA | | | -0.5 | V |
| V _{BE(ON)} | Base – Emitter On Voltage | I _C = -10mA | $V_{CE} = -10V$ | | | -1.0 | v |
| h _{FE*} | DC Current Gain | I _C = -1mA | $V_{CE} = -10V$ | 20 | | | |
| | | I _C = -10mA | $V_{CE} = -10V$ | 25 | | 200 | |
| | | I _C = -50mA | $V_{CE} = -10V$ | 20 | | | |
| f _T | Transition Frequency | I _C = -20mA | $V_{CE} = -20V$ | 100 | | 1,000 | MHz |
| | | f = 100MHz | | | | | |
| C _{cb} | Collector – Base Capacitance | V _{CB} = -20V | I _E = 0 | | | 6.0 | pF |
| | | f = 140kHz | | | | | |
| C _{eb} | Collector – Emitter Capacitance | V _{BE} = -2.0V | $I_{\rm C} = 0$ | | | 40 | |
| | | f = 140kHz | | | | | |

* Pulse test t_p = 300 μs , δ \leq 2%

 f_{T} is defined as the frequency at which h_{FE} extrapolates to unity.

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